

# **Pin Descriptions and Pin Characteristic Tables**

**Table 1. Pin Descriptions** 

Number	Name	Туре		Description
1, 2	Q0, nQ0	Output		Differential output pair. LVPECL interface levels.
3, 4	Q1, nQ1	Output		Differential output pair. LVPECL interface levels.
5	V <sub>EE</sub>	Power		Negative supply pin.
6	nCLK	Input	Pullup	Inverting differential clock input.
7	CLK	Input	Pulldown	Non-inverting differential clock input.
8	V <sub>CC</sub>	Power		Positive supply pin.

NOTE: *Pullup and Pulldown* refer to internal input resistors. See Table 2, *Pin Characteristics*, for typical values.

#### **Table 2. Pin Characteristics**

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
C <sub>IN</sub>	Input Capacitance			4		pF
R <sub>PULLUP</sub>	Input Pullup Resistor			51		kΩ
R <sub>PULLDOWN</sub>	Input Pulldown Resistor			51		kΩ



## **Absolute Maximum Ratings**

NOTE: Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These ratings are stress specifications only. Functional operation of product at these conditions or any conditions beyond those listed in the *DC Characteristics* or *AC Characteristics* is not implied. Exposure to absolute maximum rating conditions for extended periods may affect product reliability.

Item	Rating
Supply Voltage, V <sub>CC</sub>	4.6V
Inputs, V <sub>I</sub>	-0.5V to V <sub>CC</sub> + 0.5V
Outputs, I <sub>O</sub> Continuous Current Surge Current	50mA 100mA
Storage Temperature, T <sub>STG</sub>	-65°C to 150°C
Package Thermal Impedance, $\theta_{JA}$	103°C/W (0 lfpm)

### **DC Electrical Characteristics**

Table 3A. Power Supply DC Characteristics,  $V_{CC} = 3.3V \pm 5\%$  or  $2.5V \pm 5\%$ ,  $V_{EE} = 0V$ ,  $T_A = 0$ °C to 70°C

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
V <sub>CC</sub> Positive Supply Voltage	Positivo Supply Voltago		3.135	3.3	3.465	V
	Positive Supply voltage		2.375	2.5	2.625	V
I <sub>EE</sub>	Power Supply Current				25	mA

Table 3B. Differential DC Characteristics,  $V_{CC} = 3.3V \pm 5\%$  or  $2.5V \pm 5\%$ ,  $V_{EE} = 0V$ ,  $T_A = 0^{\circ}C$  to  $70^{\circ}C$ 

Symbol	Parameter		Test Conditions	Minimum	Typical	Maximum	Units
	Input High Current	nCLK	V <sub>CC</sub> = V <sub>IN</sub> = 3.465V or 2.625V			5	μΑ
Iн	Input High Current	CLK	V <sub>CC</sub> = V <sub>IN</sub> = 3.465V or 2.625V			150	μA
	Input Low Current	nCLK	V <sub>CC</sub> = 3.465V or 2.625V, V <sub>IN</sub> = 0V	-150			μA
l IIL	input Low Current	CLK	V <sub>CC</sub> = 3.465V or 2.625V, V <sub>IN</sub> = 0V	-5			μA
V <sub>PP</sub>	Peak-to-Peak Input V NOTE 1	oltage;		0.15		1.3	V
V <sub>CMR</sub>	Common Mode Input NOTE 1, 2	Voltage;		V <sub>EE</sub> + 0.5		V <sub>CC</sub> - 0.85	V

NOTE 1:  $V_{IL}$  should not be less than -0.3V.

NOTE 2: Common mode voltage is defined as  $V_{\text{IH}}$ .

Table 3C. LVPECL DC Characteristics,  $V_{CC} = 3.3V \pm 5\%$  or  $2.5V \pm 5\%$ ,  $V_{EE} = 0V$ ,  $T_A = 0$ °C to 70°C

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
V <sub>OH</sub>	Output High Current; NOTE 1		V <sub>CC</sub> – 1.4		V <sub>CC</sub> - 0.9	V
$V_{OL}$	Output Low Current; NOTE 1		V <sub>CC</sub> – 2.0		V <sub>CC</sub> – 1.7	V
V <sub>SWING</sub>	Peak-to-Peak Output Voltage Swing		0.65		1.0	V

NOTE1: Outputs terminated with  $50\Omega$  to  $\mbox{V}_{\mbox{CC}}$  –  $2\mbox{V}.$ 



## **AC Electrical Characteristics**

Table 4A. AC Characteristics,  $V_{CC} = 3.3V \pm 5\%$ ,  $V_{EE} = 0V$ ,  $T_A = 0$ °C to 70°C

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
f <sub>MAX</sub>	Maximum Output Frequency				1	GHz
t <sub>PD</sub>	Propagation Delay; NOTE 1	<i>f</i> ≤ 1GHz	0.9		1.4	ns
<i>t</i> jit	Buffer Additive Phase Jitter, RMS; refer to Additive Phase Jitter Section	156.25MHz, Integration Range (12kHz – 20MHz)		0.14		ps
tsk(o)	Output Skew; NOTE 2, 4				15	ps
tsk(pp)	Part-to-Part Skew; NOTE 3, 4				100	ps
t <sub>R</sub> / t <sub>F</sub>	Output Rise/Fall Time	20% to 80% @ 50MHz	300		700	ps
odc	Output Duty Cycle		48		52	%

NOTE: Electrical parameters are guaranteed over the specified ambient operating temperature range, which is established when device is mounted in a test socket with maintained transverse airflow greater than 500 lfpm. Device will meet specifications after thermal equilibrium has been reached under these conditions.

All parameters are measured 500MHz unless otherwise noted.

NOTE 1: Measured from the differential input crossing point to the differential output crossing point.

NOTE 2: Defined as skew between outputs at the same supply voltage and with equal load conditions. Measured at the differential cross points.

NOTE 3: Defined as skew between outputs on different devices operating at the same supply voltages and with equal load conditions. Using the same type of inputs on each device, the outputs are measured at the differential cross points.

NOTE 4: This parameter is defined in accordance with JEDEC Standard 65.

Table 4B. AC Characteristics,  $V_{CC} = 2.5V \pm 5\%$ ,  $V_{EE} = 0V$ ,  $T_A = 0$ °C to 70°C

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
f <sub>MAX</sub>	Maximum Output Frequency				1	GHz
t <sub>PD</sub>	Propagation Delay; NOTE 1	<i>f</i> ≤ 1GHz	0.9		1.4	ns
fjit	Buffer Additive Phase Jitter, RMS; refer to Additive Phase Jitter Section	156.25MHz, Integration Range (12kHz – 20MHz)		0.135		ps
tsk(o)	Output Skew; NOTE 2, 4				15	ps
tsk(pp)	Part-to-Part Skew; NOTE 3, 4				100	ps
t <sub>R</sub> / t <sub>F</sub>	Output Rise/Fall Time	20% to 80% @ 50MHz	300		700	ps
odc	Output Duty Cycle		48		52	%

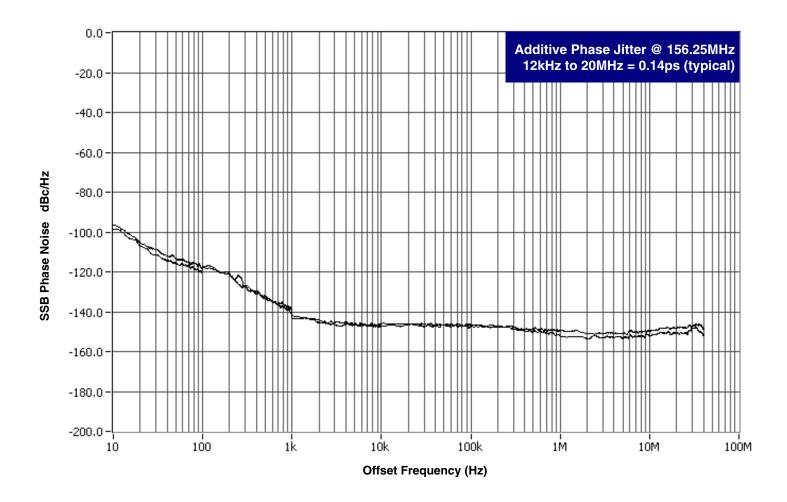
See Table 5A for NOTES.



## **Additive Phase Jitter (3.3V)**

The spectral purity in a band at a specific offset from the fundamental compared to the power of the fundamental is called the *dBc Phase Noise*. This value is normally expressed using a Phase noise plot and is most often the specified plot in many applications. Phase noise is defined as the ratio of the noise power present in a 1Hz band at a specified offset from the fundamental frequency to the power value of the fundamental. This ratio is expressed in decibels (dBm) or a ratio

of the power in the 1Hz band to the power in the fundamental. When the required offset is specified, the phase noise is called a *dBc* value, which simply means dBm at a specified offset from the fundamental. By investigating jitter in the frequency domain, we get a better understanding of its effects on the desired application over the entire time record of the signal. It is mathematically possible to calculate an expected bit error rate given a phase noise plot.

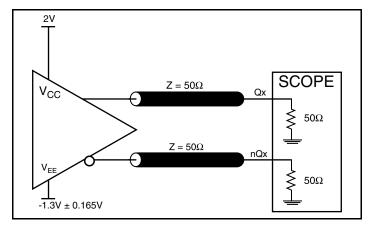


As with most timing specifications, phase noise measurements has issues relating to the limitations of the equipment. Often the noise floor of the equipment is higher than the noise floor of the device. This

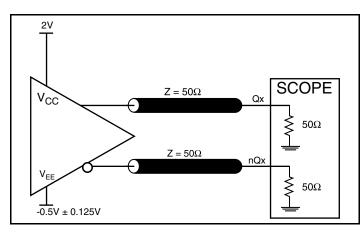
is illustrated above. The device meets the noise floor of what is shown, but can actually be lower. The phase noise is dependent on the input source and measurement equipment.



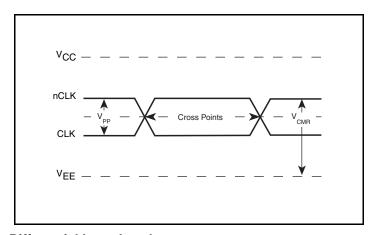
## **Parameter Measurement Information**



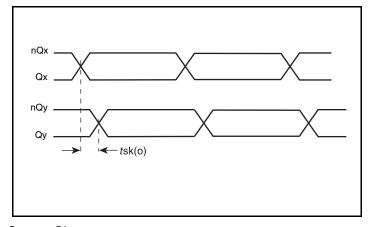
3.3V Core/ 3.3V LVPECL Output Load AC Test Circuit



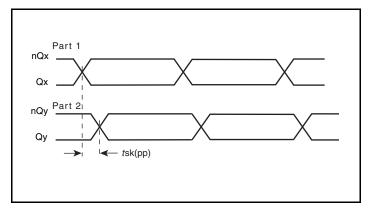
2.5V Core/ 2.5V LVPECL Output Load AC Test Circuit



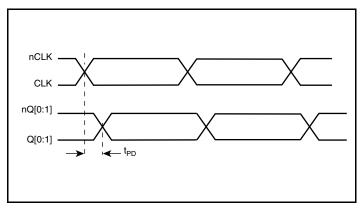
**Differential Input Level** 



**Output Skew** 



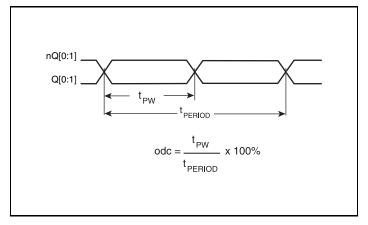
**Part-to-Part Skew** 

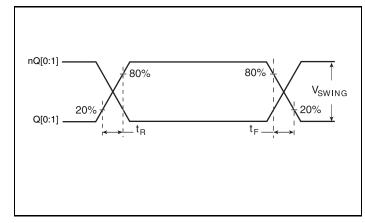


**Propagation Delay** 



## **Parameter Measurement Information, continued**





**Output Duty Cycle/Pulse Width/Period** 

**Output Rise/Fall Time** 

## **Applications Information**

### Wiring the Differential Input to Accept Single Ended Levels

Figure 1 shows how the differential input can be wired to accept single ended levels. The reference voltage V\_REF =  $V_{CC}/2$  is generated by the bias resistors R1, R2 and C1. This bias circuit should be located as close as possible to the input pin. The ratio of R1 and R2 might need to be adjusted to position the V\_REF in the center of the input voltage swing. For example, if the input clock swing is only 2.5V and  $V_{CC}$  = 3.3V, V\_REF should be 1.25V and R2/R1 = 0.609.

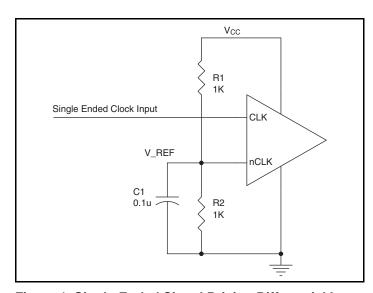


Figure 1. Single-Ended Signal Driving Differential Input



#### **Differential Clock Input Interface**

The CLK /nCLK accepts LVDS, LVPECL, LVHSTL, SSTL, HCSL and other differential signals. Both signals must meet the  $\rm V_{PP}$  and  $\rm V_{CMR}$  input requirements. Figures 2A to 2F show interface examples for the CLK/nCLK input driven by the most common driver types. The input interfaces suggested here are examples

only. Please consult with the vendor of the driver component to confirm the driver termination requirements. For example, in Figure 2A, the input termination applies for IDT's open emitter LVHSTL drivers. If you are using an LVHSTL driver from another vendor, use their termination recommendation.

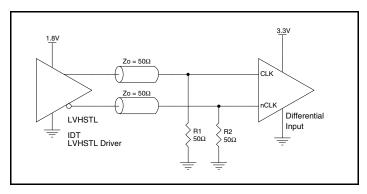


Figure 2A. CLK/nCLK Input Driven by an IDT Open Emitter LVHSTL Driver

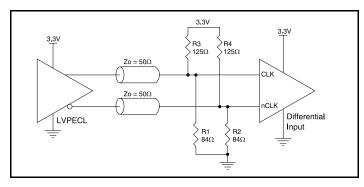


Figure 2C. CLK/nCLK Input Driven by a 3.3V LVPECL Driver

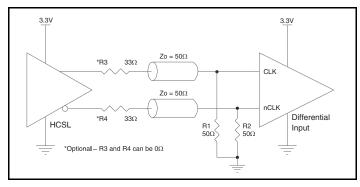


Figure 2E. CLK/nCLK Input Driven by a 3.3V HCSL Driver

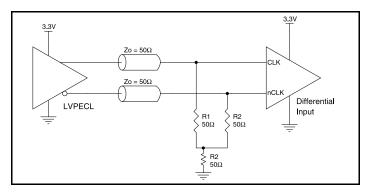


Figure 2B. CLK/nCLK Input Driven by a 3.3V LVPECL Driver

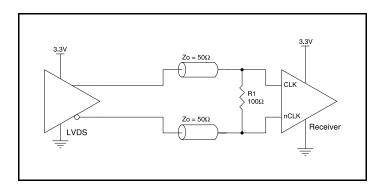


Figure 2D. CLK/nCLK Input Driven by a 3.3V LVDS Driver

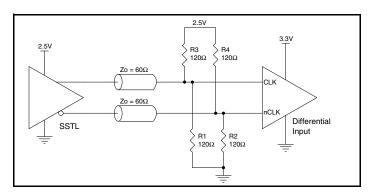


Figure 2F. CLK/nCLK Input Driven by a 2.5V SSTL Driver



### **Recommendations for Unused Output Pins**

### **Outputs:**

#### **LVPECL Outputs**

All unused LVPECL outputs can be left floating. We recommend that there is no trace attached. Both sides of the differential output pair should either be left floating or terminated.

## **Termination for 3.3V LVPECL Outputs**

The clock layout topology shown below is a typical termination for LVPECL outputs. The two different layouts mentioned are recommended only as guidelines.

FOUT and nFOUT are low impedance follower outputs that generate ECL/LVPECL compatible outputs. Therefore, terminating resistors (DC current path to ground) or current sources must be used for functionality. These outputs are designed to drive  $50\Omega$ 

transmission lines. Matched impedance techniques should be used to maximize operating frequency and minimize signal distortion. *Figures 3A and 3B* show two different layouts which are recommended only as guidelines. Other suitable clock layouts may exist and it would be recommended that the board designers simulate to guarantee compatibility across all printed circuit and clock component process variations.

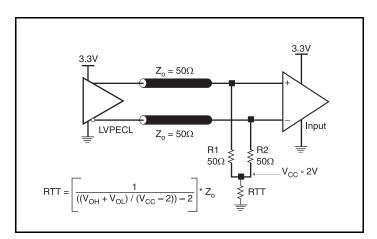


Figure 3A. 3.3V LVPECL Output Termination

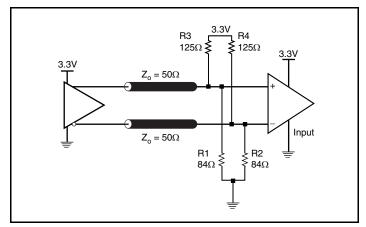


Figure 3B. 3.3V LVPECL Output Termination



## **Termination for 2.5V LVPECL Outputs**

Figure 4A and Figure 4B show examples of termination for 2.5V LVPECL driver. These terminations are equivalent to terminating  $50\Omega$  to  $V_{CC}-2V$ . For  $V_{CC}=2.5V$ , the  $V_{CC}-2V$  is very close to ground

level. The R3 in Figure 4B can be eliminated and the termination is shown in *Figure 4C*.

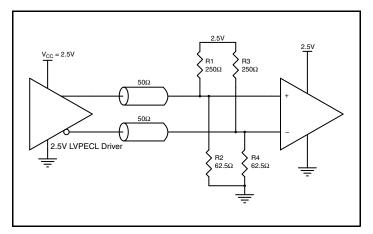


Figure 4A. 2.5V LVPECL Driver Termination Example

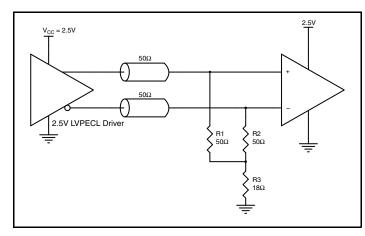


Figure 4B. 2.5V LVPECL Driver Termination Example

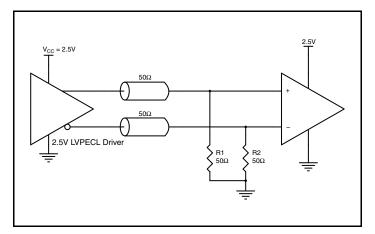


Figure 4C. 2.5V LVPECL Driver Termination Example



#### **Power Considerations**

This section provides information on power dissipation and junction temperature for the 85311. Equations and example calculations are also provided.

#### 1. Power Dissipation.

The total power dissipation for the 85311 is the sum of the core power plus the power dissipated in the load(s).

The following is the power dissipation for  $V_{CC} = 3.3V + 5\% = 3.465V$ , which gives worst case results.

NOTE: Please refer to Section 3 for details on calculating power dissipated in the load.

- Power (core)<sub>MAX</sub> = V<sub>CC MAX</sub> \* I<sub>EE MAX</sub> = 3.465V \* 25mA = 86.6mW
- Power (outputs)<sub>MAX</sub> = 30mW/Loaded Output pair
   If all outputs are loaded, the total power is 2 \* 30mW = 60mW

Total Power\_MAX (3.3V, with all outputs switching) = 86.6mW + 60mW = 146.6mW

#### 2. Junction Temperature.

Junction temperature, Tj, is the temperature at the junction of the bond wire and bond pad and directly affects the reliability of the device. The maximum recommended junction temperature for devices is 125°C.

The equation for Tj is as follows: Tj =  $\theta_{JA}$  \* Pd\_total + T<sub>A</sub>

Tj = Junction Temperature

 $\theta_{JA}$  = Junction-to-Ambient Thermal Resistance

Pd\_total = Total Device Power Dissipation (example calculation is in section 1 above)

T<sub>A</sub> = Ambient Temperature

In order to calculate junction temperature, the appropriate junction-to-ambient thermal resistance  $\theta_{JA}$  must be used. Assuming no air flow and a multi-layer board, the appropriate value is 103°C/W per Table 5 below.

Therefore, Tj for an ambient temperature of 70°C with all outputs switching is:

 $70^{\circ}\text{C} + 0.147\text{W} * 103^{\circ}\text{C/W} = 85.14^{\circ}\text{C}$ . This is well below the limit of  $125^{\circ}\text{C}$ .

This calculation is only an example. Tj will obviously vary depending on the number of loaded outputs, supply voltage, air flow and the type of board (single layer or multi-layer).

Table 5. Thermal Resistance  $\theta_{JA}$  for 8 Lead SOIC, Forced Convection

θ <sub>JA</sub> vs. Air Flow				
Linear Feet per Minute	0	200	500	
Multi-Layer PCB, JEDEC Standard Test Boards	103°C/W	94°C/W	89°C/W	



#### 3. Calculations and Equations.

The purpose of this section is to derive the power dissipated into the load.

LVPECL output driver circuit and termination are shown in Figure 5.

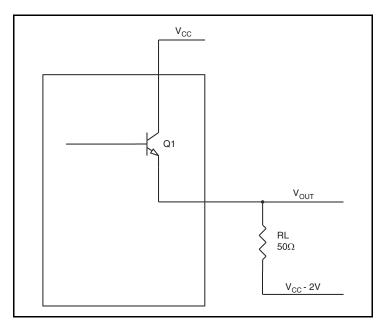


Figure 5. LVPECL Driver Circuit and Termination

To calculate worst case power dissipation into the load, use the following equations which assume a  $50\Omega$  load, and a termination voltage of  $V_{CC} - 2V$ .

- For logic high, V<sub>OUT</sub> = V<sub>OH\_MAX</sub> = V<sub>CC\_MAX</sub> 0.9V
   (V<sub>CC\_MAX</sub> V<sub>OH\_MAX</sub>) = 0.9V
- For logic low, V<sub>OUT</sub> = V<sub>OL\_MAX</sub> = V<sub>CC\_MAX</sub> 1.7V
   (V<sub>CC\_MAX</sub> V<sub>OL\_MAX</sub>) = 1.7V

Pd\_H is power dissipation when the output drives high.

Pd\_L is the power dissipation when the output drives low.

$$Pd_{-}H = [(V_{OH\_MAX} - (V_{CC\_MAX} - 2V))/R_{L}] * (V_{CC\_MAX} - V_{OH\_MAX}) = [(2V - (V_{CC\_MAX} - V_{OH\_MAX}))/R_{L}] * (V_{CC\_MAX} - V_{OH\_MAX}) = [(2V - 0.9V)/50\Omega] * 0.9V = 19.8mW$$

$$Pd_{L} = [(V_{OL\_MAX} - (V_{CC\_MAX} - 2V))/R_{L}] * (V_{CC\_MAX} - V_{OL\_MAX}) = [(2V - (V_{CC\_MAX} - V_{OL\_MAX}))/R_{L}] * (V_{CC\_MAX} - V_{OL\_MAX}) = [(2V - 1.7V)/50\Omega] * 1.7V = 10.2mW$$

Total Power Dissipation per output pair = Pd\_H + Pd\_L = 30mW



# **Reliability Information**

Table 6.  $\theta_{\text{JA}}$  vs. Air Flow Table for a 8 Lead SOIC

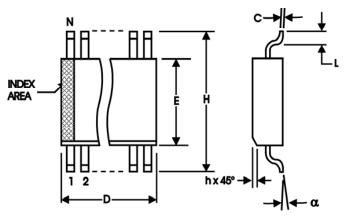
θ <sub>JA</sub> by Velocity					
Linear Feet per Minute	0	200	500		
Multi-Layer PCB, JEDEC Standard Test Boards	103°C/W	94°C/W	89°C/W		

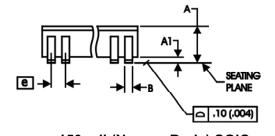
#### **Transistor Count**

The transistor count for 85311 is: 225

# **Package Outline and Package Dimensions**

Package Outline - M Suffix for 8 Lead SOIC





**Table 7. Package Dimensions** 

All Din	All Dimensions in Millimeters						
Symbol	Minimum Maximum						
N		8					
Α	1.35	1.75					
<b>A</b> 1	0.10	0.25					
В	0.33	0.51					
С	0.19	0.25					
D	4.80	5.00					
E	3.80	4.00					
е	1.27	Basic					
Н	5.80	6.20					
h	0.25	0.50					
L	0.40 1.27						
α	0°	8°					

Reference Document: JEDEC Publication 95, MS-012



# **Ordering Information**

## **Table 8. Ordering Information**

Part/Order Number Marking		Package	Shipping Packaging	Temperature
85311AMLF	85311ALF	"Lead-Free" 8 Lead SOIC	Tube	0°C to 70°C
85311AMLFT	85311ALF	"Lead-Free" 8 Lead SOIC	Tape & Reel	0°C to 70°C



# **Revision History Sheet**

Rev	Table	Page	Description of Change	Date
Α		8	Added Termination for LVPECL Outputs section.	5/30/02
А		5 7	3.3V Output Load Test Circuit Diagram - corrected VEE equation to read -1.3V $\pm$ 0.165V from $\pm$ 0.135V. Updated Output Rise/Fall Time Diagram.	9/23/02
В	T2 T8	1 2 3 3 5 6 7 8 13	Add Lead-Free bullet in Features section.  Pin Characteristics table - changed C <sub>IN</sub> 4pF max. to 4pF typical.  Absolute Maximum Ratings, updated Outputs rating.  Combined 3.3V & 2.5V Power tables and Differential DC Characteristics tables.  Updated Parameter Measurement Information.  Updated Single Ended Signal Driving Differential Input diagram.  Added Termination for 2.5V LVPECL Output section.  Added Differential Clock Input Interface section.  Ordering Information table - added Lead Free part number.	6/17/04
В	Т8	7 13	Added Recommendations for Unused Input and Output Pins. Ordering Information Table - corrected Lead-Free marking and added Lead-Free Note.	7/28/05
С	Т3	3 9 - 10	LVPECL DC Characteristics Table -corrected $V_{OH}$ max. from $V_{CC}$ - 1.0V to $V_{CCO}$ - 0.9V; and $V_{SWING}$ max. from 0.9V to 1.0V. Power Considerations - corrected power dissipation to reflect VOH max in Table 3C.	4/11/07
D	T4A - T4B	4 5 8	Added 2.5V AC Characteristics Table. Added Additive Phase Jitter spec to both AC Tables. Added Additive Phase Jitter plot. Updated Differential Input Clock Interface section.	10/22/08
D	T8	14	Ordering Information - removed leaded devices. Updated data sheet format.	7/8/15
Е	T6 T8	11 13 14	Power Considerations - updated Junction Temperature section and corrected Table 5, Thermal Resistance Table. Corrected table. Ordering Information Table - deleted table note. Deleted HiperClockS reference throughout the datasheet. Updated datasheet header/footer.	2/16/16



#### **IMPORTANT NOTICE AND DISCLAIMER**

RENESAS ELECTRONICS CORPORATION AND ITS SUBSIDIARIES ("RENESAS") PROVIDES TECHNICAL SPECIFICATIONS AND RELIABILITY DATA (INCLUDING DATASHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS OR IMPLIED, INCLUDING, WITHOUT LIMITATION, ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE, OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for developers skilled in the art designing with Renesas products. You are solely responsible for (1) selecting the appropriate products for your application, (2) designing, validating, and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, or other requirements. These resources are subject to change without notice. Renesas grants you permission to use these resources only for development of an application that uses Renesas products. Other reproduction or use of these resources is strictly prohibited. No license is granted to any other Renesas intellectual property or to any third party intellectual property. Renesas disclaims responsibility for, and you will fully indemnify Renesas and its representatives against, any claims, damages, costs, losses, or liabilities arising out of your use of these resources. Renesas' products are provided only subject to Renesas' Terms and Conditions of Sale or other applicable terms agreed to in writing. No use of any Renesas resources expands or otherwise alters any applicable warranties or warranty disclaimers for these products.

(Rev.1.0 Mar 2020)

## **Corporate Headquarters**

TOYOSU FORESIA, 3-2-24 Toyosu, Koto-ku, Tokyo 135-0061, Japan www.renesas.com

#### **Trademarks**

Renesas and the Renesas logo are trademarks of Renesas Electronics Corporation. All trademarks and registered trademarks are the property of their respective owners.

#### **Contact Information**

For further information on a product, technology, the most up-to-date version of a document, or your nearest sales office, please visit:

www.renesas.com/contact/

# **Mouser Electronics**

**Authorized Distributor** 

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

Renesas Electronics: 85311AMLFT